



#### **DUAL NPN SMALL SIGNAL SURFACE MOUNT TRANSISTOR**

#### **Features**

- BV<sub>CEO</sub> >45V
- Ultra-Small Surface Mount Package
- Ideally Suited for Automated Insertion
- For switching and AF Amplifier Application
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The BC847BSQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

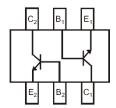
#### **Mechanical Data**

- Case: SOT363
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Finish. Solderable per MIL-STD-202, Method 208 <sup>3</sup>
- Weight: 0.006 grams (Approximate)





Top View



**Device Schematic** 

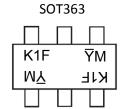
#### **Ordering Information** (Note 4)

Part Number	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
BC847BSQ-7-F	Automotive	K1F	7	8	3,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2 See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

# Marking Information



K1F = Product Type Marking Code (See Ordering Information) YM = Date Code Marking

 $\overline{Y}$  or Y = Year (ex: I = 2021)

M = Month (ex: 9 = September)

Date Code Kev

Year	2021	2022	2023	2024	2025	2026	2027	2028	2029	2030	2031	2032
Code	ı	J	K	L	М	N	0	Р	R	S	Т	J
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec

BC847BSQ Document number: DS43231 Rev. 3 - 2



## **Absolute Maximum Ratings** (@ T<sub>A</sub> = +25°C unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	50	V
Collector-Emitter Voltage	V <sub>CEO</sub>	45	V
Emitter-Base Voltage	V <sub>EBO</sub>	6	V
Collector Current	Ic	100	mA
Peak Pulse Collector Current	I <sub>CM</sub>	200	mA
Peak Pulse Base Current	I <sub>BM</sub>	200	mA

#### Thermal Characteristics (@ T<sub>A</sub> = +25°C unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Power Dissipation (Note 5)	$P_{D}$	200	mW	
Thermal Resistance, Junction to Ambient (Note 5)	$R_{ hetaJA}$	625	°C/W	
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C	

### Electrical Characteristics (@ T<sub>A</sub> = +25°C unless otherwise specified.)

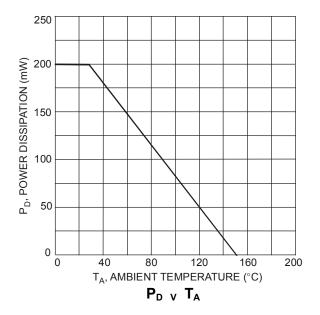
Characteristic (Note 6)	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	50	-		٧	$I_C = 100 \mu A, I_B = 0$
Collector-Emitter Breakdown Voltage	BV <sub>CEO</sub>	45	_	_	V	$I_C = 10mA, I_B = 0$
Emitter-Base Breakdown Voltage	$BV_{EBO}$	6			V	$I_E = 100 \mu A, I_C = 0$
DC Current Gain	h <sub>FE</sub>	200	1	450		$V_{CE} = 5.0V, I_{C} = 2.0mA$
Collector-Emitter Saturation Voltage	V <sub>CE(sat)</sub>		1	100 400	mV	$I_C = 10$ mA, $I_B = 0.5$ mA $I_C = 100$ mA, $I_B = 5.0$ mA
Base-Emitter Saturation Voltage	V <sub>BE(sat)</sub>	1	755		mV	$I_C = 10mA, I_B = 0.5mA$
Base-Emitter Voltage	V <sub>BE(on)</sub>	580	665	700	mV	V <sub>CE</sub> = 5.0V, I <sub>C</sub> = 2.0mA
Collector-Cut Off Current	I <sub>CBO</sub>			20 5.0	nΑ μΑ	V <sub>CB</sub> = 40V V <sub>CB</sub> = 40V, T <sub>A</sub> = +125°C
Emitter-Cut Off Current	I <sub>EBO</sub>		_	100	nA	$V_{EB} = 5.0V, I_{C} = 0$
Gain Bandwidth Product	f <sub>T</sub>	100	_	_	MHz	V <sub>CE</sub> = 5.0V, I <sub>C</sub> = 10mA, f = 100MHz
Collector-Base Capacitance	C <sub>CBO</sub>	1	2.0	3.0	pF	V <sub>CB</sub> = 10V, f = 1.0MHz
Emitter-Base Capacitance	C <sub>EBO</sub>	_	11	_	pF	V <sub>EB</sub> = 0.5V, f = 1.0MHz

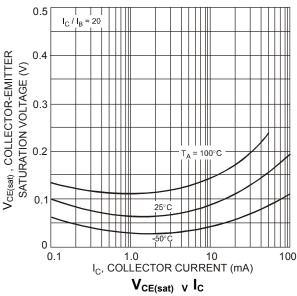
5. For the device mounted on minimum recommended pad layout FR4 PCB with high coverage of single sided 1oz copper, in still air conditions; the device Notes: is measured when operating in a steady-state condition.

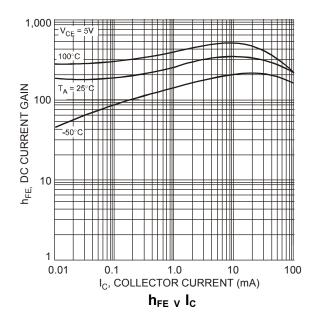
6. Short duration pulse test used to minimize self-heating effect.

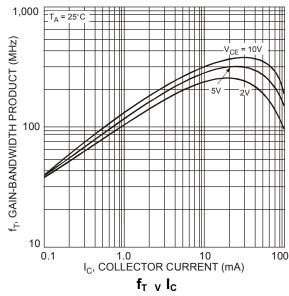


### Typical Electrical Characteristics (@ T<sub>A</sub> = +25°C unless otherwise specified.)





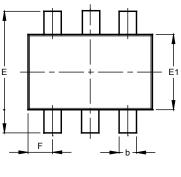


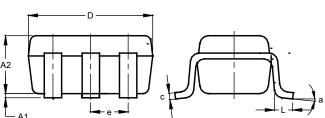




# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

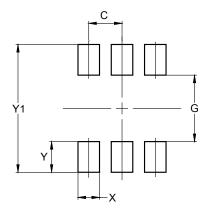




SOT363							
Dim	Min	Max	Тур				
<b>A</b> 1	0.00	0.10	0.05				
A2	0.90	1.00	1.00				
b	0.10	0.30	0.25				
С	0.10	0.22	0.11				
D	1.80	2.20	2.15				
Е	2.00	2.20	2.10				
E1	1.15	1.35	1.30				
е	e 0.650 BSC						
F	0.40	0.45	0.425				
L	0.25	0.40	0.30				
а	0°	8°					
All Dimensions in mm							

## **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)		
С	0.650		
G	1.300		
X	0.420		
Y	0.600		
Y1	2 500		



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